

#### **Features**

- · Split Gate Trench MOSFET Technology
- · Low Thermal Resistance
- · Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## **Maximum Ratings**

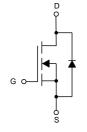
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 0.85°C/W Junction to Case<sup>(2)</sup>

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Volltage	V <sub>GS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	100	Α
Pulsed Drain Current <sup>(3)</sup>	I <sub>DM</sub>	240	Α
Total Power Dissipation	P <sub>D</sub>	147	W
Single Pulsed Avalanche Energy <sup>(4)</sup>	E <sub>AS</sub>	800	mJ

#### Note:

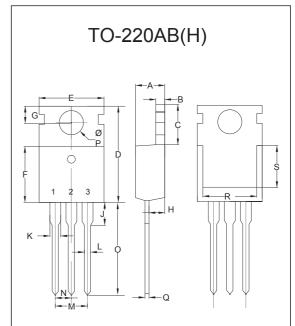
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. Surface Mounted on 1 in  $^2$  pad area, t  $\leq$ 10 sec
- 3. Pulse Test: Pulse Width  $\leq$  300us, Duty cycle  $\leq$  2%.
- 4.  $T_J=25$ °C,  $V_{DD}=50$ V, L=1.0mH.

#### **Internal Structure**



- 1. Gate
- 2. Drain
- 3. Source

# N-CHANNEL MOSFET



DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOIL	
Α	0.172	0.188	4.37	4.77		
В	0.049	0.057	1.25	1.45		
С	0.246	0.270	6.25	6.85		
D	0.594	0.634	15.10	16.10		
Е	0.382	0.406	9.70	10.30		
F	0.346	0.370	8.80	9.40		
G	0.102	0.118	2.60	3.00		
Н	0.087	0.102	2.20	2.60		
J		0.134		3.40		
K	0.046	0.058	1.17	1.47		
L	0.028	0.037	0.70	0.95		
М	0.2	200	5.	08	TYP.	
N	0.100		2.54		TYP.	
0	0.502	0.543	12.75	13.80		
Р	0.134	0.150	3.40	3.80	Ф	
Q	0.016	0.026	0.40	0.65		
R	0.276		7.00			
S	0.217		5.50			

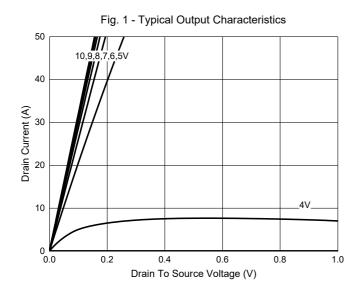


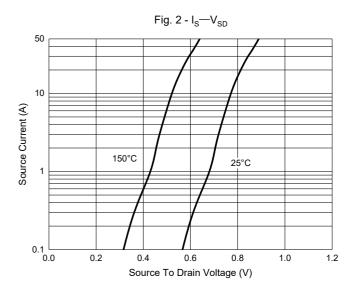
# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

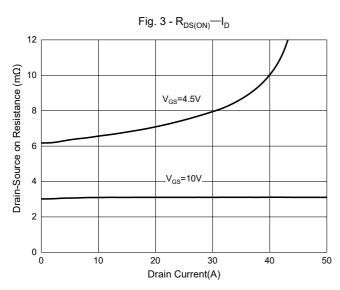
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics			1				
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	100			V	
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{DS}$ =0V, $V_{GS}$ =±20V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =80V, V <sub>GS</sub> =0V			1	μΑ	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2		4	V	
Drain-Source On-Resistance		V <sub>GS</sub> =10V, I <sub>D</sub> =20A		2.9	3.5	mΩ	
	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A		6.6	8.5	mΩ	
Diode Characteristics			,				
Continuous Body Diode Current	Is				100	Α	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =20A			1.3	V	
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =20A, dI <sub>F</sub> /dt=100A/μs		96		ns	
Reverse Recovery Charge	Q <sub>rr</sub>	i <sub>F</sub> =20A, αi <sub>F</sub> /αι-100A/μs		233		nC	
Dynamic Characteristics				•	•		
Input Capacitance	C <sub>iss</sub>			6897			
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,f=1MHz		1039		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			27			
Total Gate Charge	Qg			122			
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =10V,I <sub>D</sub> =20A		32		nC	
Gate-Drain Charge	$Q_{gd}$			31			
Turn-On Delay Time	t <sub>d(on)</sub>			26			
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =50V, $V_{GEN}$ =10V, $R_{G}$ =4.5 $\Omega$ , $R_{L}$ =2.5 $\Omega$ ,		55		ne	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_{DS}=20A$		72		ns	
Turn-Off Fall Time	t <sub>f</sub>			66			

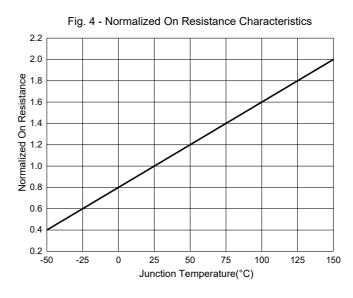


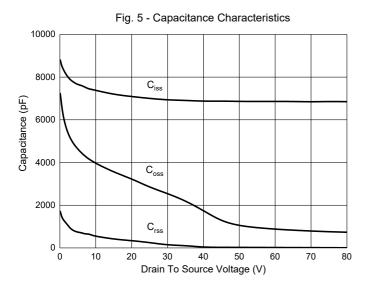
#### **Curve Characteristics**

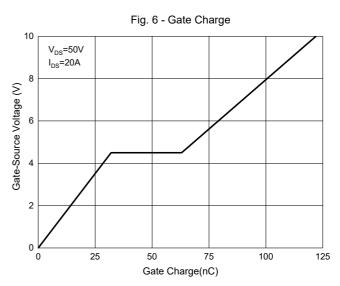






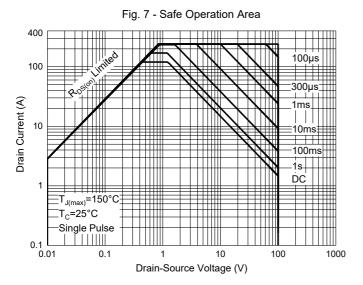








### **Curve Characteristics**





# **Ordering Information**

Device	Packing		
Part Number-BP	Bulk: 50pcs/Tube; 1Kpcs/Box; 5Kpcs/Ctn		

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